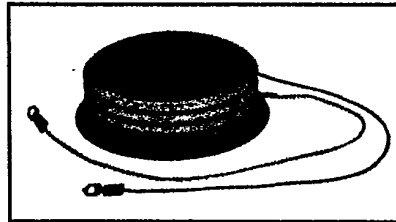
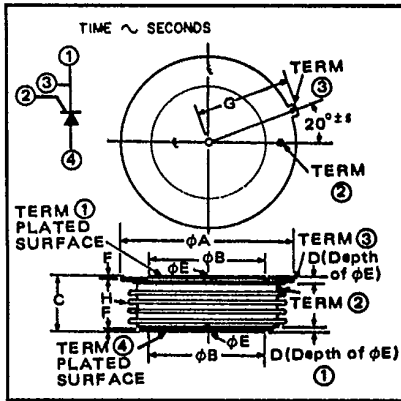




**C781**

Powerex, Inc. Hills Street, Youngwood, Pennsylvania 15897 (412) 925-7272  
 Powerex Europe, S.A., 428 Ave. G. Durand, BP107, 72003 LeMans, France (43) 72.75.15

**Phase Control SCR**  
 2500 Amperes Avg  
 1600-2100 Volts



**C781**  
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 2500 Amperes/1600-2100 Volts

**C781**  
**Outline Drawing**

Dimensions	Inches		Millimeters	
	Min.	Max.	Min.	Max.
$\phi A$	—	4.350	—	110.49
$\phi B$	2.876	2.830	73.05	73.15
C	1.387	1.447	35.23	36.75
D	.080	—	2.03	—
$\phi E$	0.136	0.146	3.45	3.71
F	0.20	—	5.08	—
G	2.403	2.418	61.16	61.42
H	—	—	—	—

**Description**

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, Press-Pak (Pow-R-Disc) devices employing the field-proven amplifying (di/namic) gate.

**Features:**

- Low On-State Voltage
- High di/dt
- High dv/dt
- Hermetic Packaging
- Excellent Surge and I<sup>2</sup>t Ratings

**Applications:**

- Power Supplies
- Battery Chargers
- Motor Control
- Light Dimmers
- VAR Generators

**Ordering Information**

Example: Select the complete five or six digit part number you desire from the table - i.e. C781L is a 2000 Volt, 2500 Ampere Phase Control SCR.

Type	Voltage		Current
	V <sub>ORM</sub> V <sub>RRM</sub>	Code	
C781	1600	PM	2500
	1700	PS	
	1800	PN	
	1900	PT	
	2000	L	
	2100	LA	



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### Absolute Maximum Ratings

	Symbol	C781	Units
RMS On-State Current	$I_{T(RMS)}$	3925	Amperes
Average On-State Current	$I_{T(av)}$	2500	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	$I_{TSM}$	45,000	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	$I_{TSM}$	41,500	Amperes
Critical Rate-of-Rise of On-State Current (Non-Repetitive)	di/dt	600	Amperes/ $\mu$ s
Critical Rate-of-Rise of On-State Current (Repetitive)	di/dt	100	Amperes/ $\mu$ s
$I^2t$ (for Fusing), One Cycle at 60Hz	$I^2t$	$8.5 \times 10^6$	A <sup>2</sup> sec
Peak Gate Power Dissipation, 100 microseconds	$P_{GM}$	250	Watts
Average Gate Power Dissipation	$P_{G(av)}$	35	Watts
Storage Temperature	$T_{STG}$	-40 to 150	°C
Operating Temperature	$T_J$	-40 to 125	°C
Mounting Force <sup>Ⓞ</sup>		9000 to 10,000	lb.
Mounting Force <sup>Ⓞ</sup>		40 to 44.5	kN

### Electrical and Thermal Characteristics

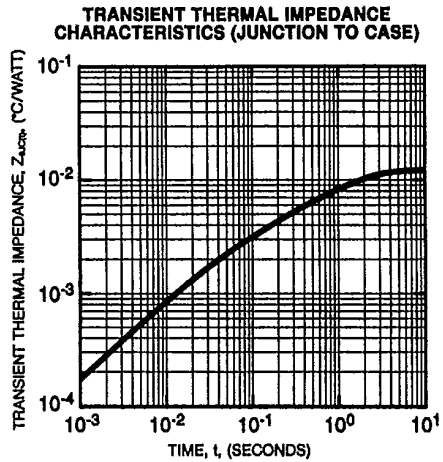
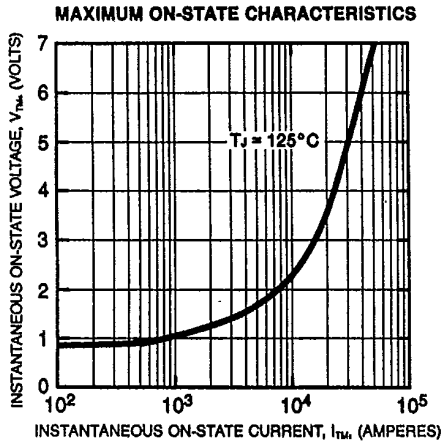
Characteristics	Symbol	Test Conditions	C781	Units
<b>Voltage—Blocking State Maximums</b>				
Forward Leakage, Peak	$I_{DRM}$	$T_J = 125^\circ\text{C}, V_{DRM} = \text{Rated}$	150	mA
Reverse Leakage, Peak	$I_{RRM}$	$T_J = 125^\circ\text{C}, V_{RRM} = \text{Rated}$	150	mA
<b>Current—Conducting State Maximums</b>				
Peak On-State Voltage	$V_{TM}$	$T_J = 125^\circ\text{C}, I_{TM} = 2000\text{A}$	1.20	Volts
<b>Switching</b>				
Typical Turn-Off Time	$t_q$	$T_J = 125^\circ\text{C}, I_T = 2000\text{A}$ $t_p > 3\text{ms}$ $di_R/dt = 5\text{A } \mu\text{s}$ $V_R = 100\text{V}$ $dv/dt = 1000\text{V } \mu\text{s}$ $V \text{ reapplied} = 1000\text{V}$	250	$\mu\text{sec}$
Typical Delay Time	$t_d$	$T_J = 125^\circ\text{C}, V_D = 1500\text{V}$	3	$\mu\text{sec}$
Min. Critical dv/dt exponential to $V_{DRM}$	dv/dt	$T_J = 125^\circ\text{C}, V_D = .8V_{DRM}$	500	V/ $\mu\text{sec}$
<b>Thermal</b>				
Maximum Thermal Resistance, <sup>Ⓞ</sup> double sided cooling				
Junction to Case	$R_{\theta JC}$		.012	°C/Watt
Case to Sink, Lubricated	$R_{\theta CS}$		.002	°C/Watt
<b>Gate—Maximum Parameters</b>				
Gate Current to Trigger	$I_{GT}$	$T_J = 25^\circ\text{C}, V_D = 12\text{Vdc}$	250	mA
Gate Voltage to Trigger	$V_{GT}$	$T_J = 25^\circ\text{C}, V_D = 12\text{Vdc}$	4.2	Volts
Non-Triggering Gate Voltage	$V_{GDM}$	$T_J = 125^\circ\text{C}, V_D = 1000\text{V}$	.5	Volts
Peak Forward Gate Current	$I_{GTM}$		20	Amperes
Peak Reverse Gate Voltage	$V_{GRM}$		20	Volts

<sup>Ⓞ</sup> Consult recommended mounting procedures.

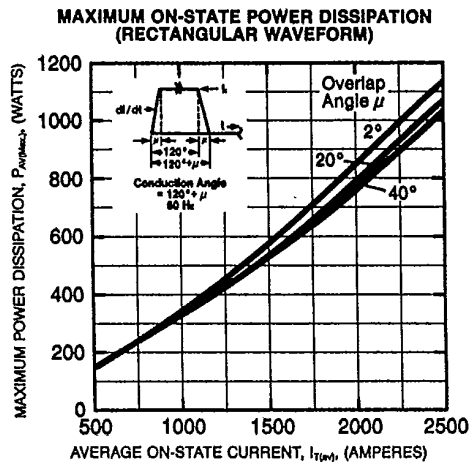
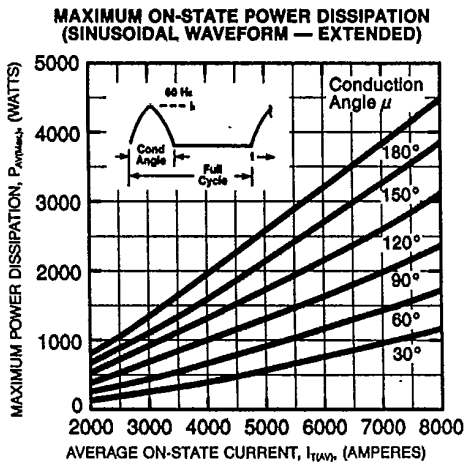
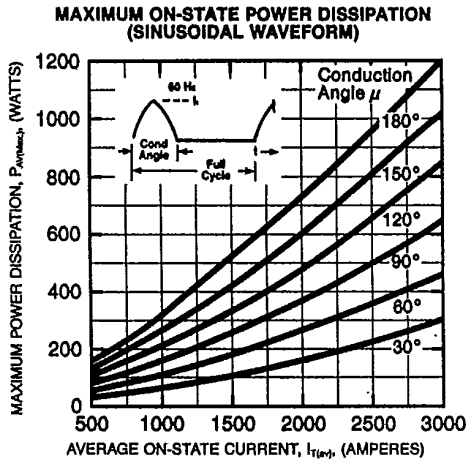


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- NOTES:**
1. Add .002°C/W to account for both case to dissipator interfaces when properly mounted; e.g.  $R_{\theta jc} = .014^\circ\text{C/W}$ . See Mounting Instructions.
  2. DC Thermal Impedance is based on average full cycle junction temperature. Instantaneous junction temperature may be calculated using the following modifications:
    - end of conducting portion of cycle
    - 120° sq. wave add .0012°C/W along entire curve
    - 180° sq. wave add .0010°C/W along entire curve
    - 180° sine wave add .0005°C/W along entire curve
    - end of full cycle
    - any wave, subtract .0005°C/W along entire curve
  3. Ask for general mounting instructions.





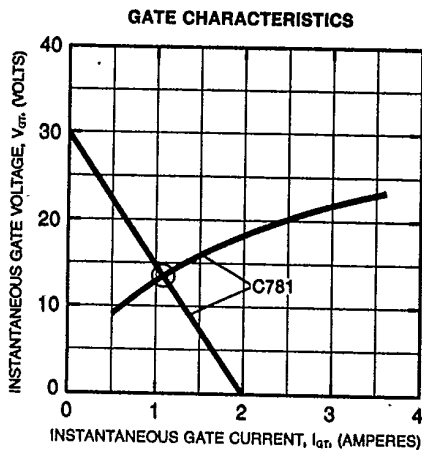
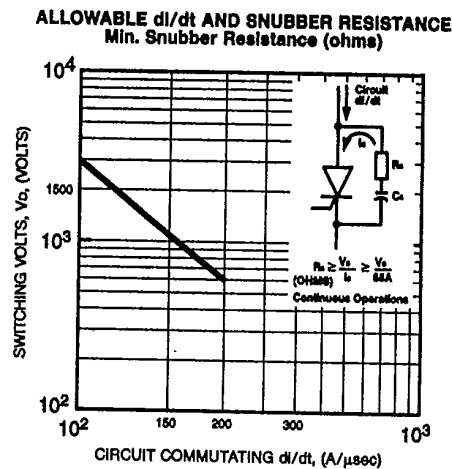
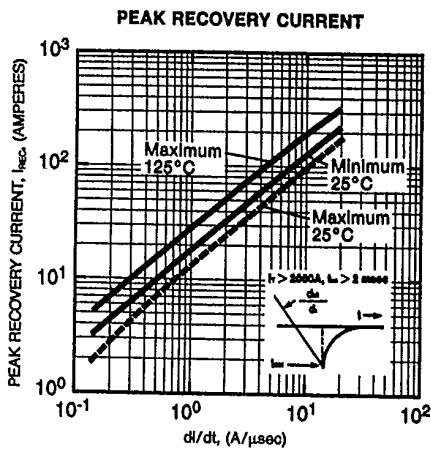
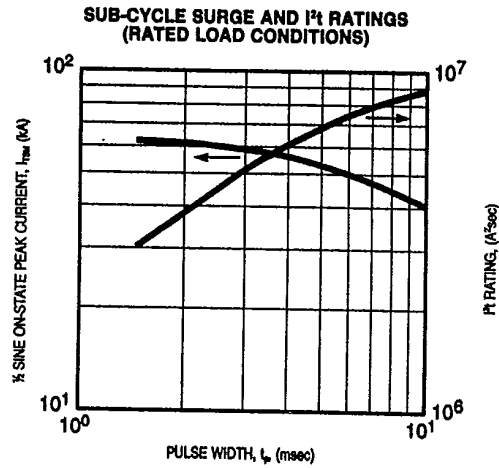
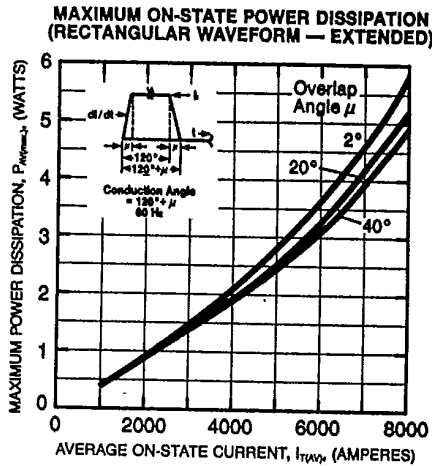
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**NOTES:**

**Thyristor Gate Impedance**

- This is enhanced by fast rising gate voltage, increasing anode bias and temperature.
- It is at a minimum for dc voltage, zero bias and low temperature (not shown).
- The maximum impedances expected for C784 and C781, C782 are indicated as curves of gate current versus gate voltage.

**Gate Supply**

- Load lines for 40V/10 $\Omega$  and 30V/15 $\Omega$  are shown. The short circuit current rise time should be approximately 0.5 $\mu$ s and the duration longer than the delay time expected for the thyristor.

**Minimum Acceptable Gate Current**

- The intersection of load line and gate characteristic (enriched) indicates the minimum value of actual current flowing into the gate that is required during the delay time interval needed for the published  $dI/dt$  and snubber discharge ratings.

**Additional**

- Peak gate power,  $P_{G(av)}$  (100 $\mu$ s) ..... 250W
- Average gate power,  $P_{G(av)}$  ..... 35W
- Peak gate current ..... 20A
- Peak reverse voltage  $V_{orav}$  ..... 30V